

### High power NPN epitaxial planar bipolar transistor

#### **Features**

- High breakdown voltage V<sub>CEO</sub> = 250 V
- Complementary to 2ST2121
- Fast-switching speed
- Typical f<sub>t</sub> = 25 MHz
- Fully characterized at 125 °C

### **Applications**

■ Audio power amplifier

#### **Description**

The device is a NPN transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.

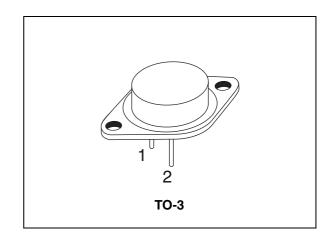


Figure 1. Internal schematic diagram

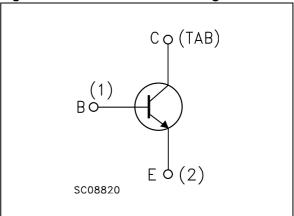


Table 1. Device summary

Order code	Marking	Package	Packaging
2ST5949	2ST5949	TO-3	tray

Electrical ratings 2ST5949

# 1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base voltage (I <sub>E</sub> = 0)	250	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	250	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	6	V
I <sub>C</sub>	Collector current	17	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	34	Α
P <sub>TOT</sub>	Total dissipation at T <sub>c</sub> = 25°C	250	W
T <sub>stg</sub>	Storage temperature	-65 to 200	°C
TJ	Max. operating junction temperature	200	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case max	0.7	°C/W

2ST5949 Electrical characteristics

## 2 Electrical characteristics

 $(T_{case} = 25^{\circ}C; unless otherwise specified)$ 

Table 4. Electrical characteristics

Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current $(I_E = 0)$	V <sub>CB</sub> = 250 V				5	μΑ
I <sub>EBO</sub>	Emitter cut-off current $(I_C = 0)$	V <sub>EB</sub> = 6 V				5	μΑ
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 50 mA		250			V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	I <sub>C</sub> = 100 μA		250			V
V <sub>(BR)EBO</sub> <sup>(1)</sup>	Emitter-base breakdown voltage $(I_C = 0)$	I <sub>E</sub> = 1 mA		6			V
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	I <sub>C</sub> = 8 A	I <sub>B</sub> = 800 mA			3	V
V <sub>BE</sub> <sup>(1)</sup>	Base-emitter on voltage	I <sub>C</sub> = 7 A	$V_{CE} = 5 V$			1.5	٧
h <sub>FE</sub>	IDC ourront gain	I <sub>C</sub> = 1 A I <sub>C</sub> = 7 A	$V_{CE} = 5 V$ $V_{CE} = 5 V$	80 35		160	
f <sub>T</sub>	Transition frequency	I <sub>C</sub> = 1 A	V <sub>CE</sub> = 5 V		25		MHz

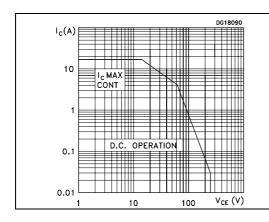
<sup>1.</sup> Pulsed duration = 300 μs, duty cycle ≤1.5%

Electrical characteristics 2ST5949

## 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve



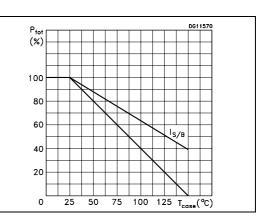
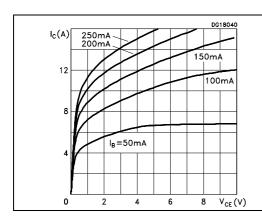


Figure 4. Output characteristics

Figure 5. DC current gain



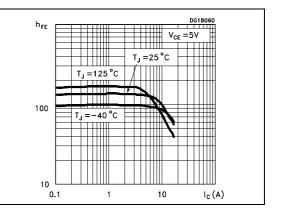
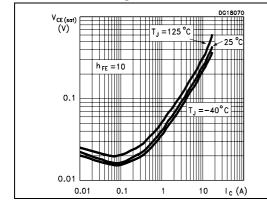
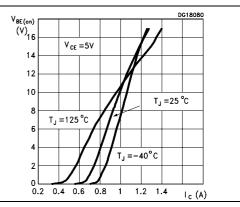


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter on voltage



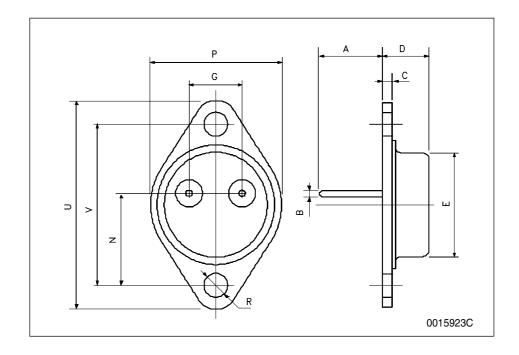


## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

#### TO-3 mechanical data

DIM.	mm.				
DIM.	min.	typ	max.		
А	11.00		13.10		
В	0.97		1.15		
С	1.50		1.65		
D	8.32		8.92		
E	19.00		20.00		
G	10.70		11.10		
N	16.50		17.20		
Р	25.00		26.00		
R	4.00		4.09		
U	38.50		39.30		
V	30.00		30.30		



2ST5949 Revision history

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
05-Dec-2007	1	Initial release.
05-May-2008	2	New graphics. Updated figure 7 and maximum operating junction temperature value.
11-Jul-2008	3	Updated figure 7 and maximum operating junction temperature value.

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